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Engineering the Palladium-WSe₂ Interface Chemistry for Field Effect Transistors with High-Performance Hole Contacts

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Citation:

Smyth, Christopher M., Lee A. Walsh, Pavel Bolshakov, Massimo Catalano, et al. 2019. "Engineering the Palladium-WSe₂ Interface Chemistry for Field Effect Transistors with High-Performance Hole Contacts." ACSA Applied Nano Materials 2(1): 75-88, doi: 10.1021/acsanm.8b01708

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